Dual/Quad Low-Power 100MHz Gain-of-2 Stable Op Amp

The EL2245 and EL2445 are dual and quad versions of the popular EL2045. They are high speed, low power, low cost monolithic operational amplifiers built on Elantec's proprietary complementary bipolar process. The EL2245 and EL2445 are gain-of-2 stable and feature a 275V/µs slew rate and 100MHz bandwidth at gain-of-2 while requiring only 5.2mA of supply current per amplifier.

The power supply operating range of the EL2245 and EL2445 is from ±18V down to as little as ±2V. For single-supply operation, the EL2245 and EL2445 operate from 36V down to as little as 2.5V. The excellent power supply operating range of the EL2245 and EL2445 makes them an obvious choice for applications on a single +5V or +3V supply.

The EL2245 and EL2445 also feature an extremely wide output voltage swing of ±13.6V with V_S = ±15V and R_L = 1kΩ. At ±5V, output voltage swing is a wide ±3.8V with R_L = 500Ω and ±3.2V with R_L = 150Ω. Furthermore, for single-supply operation at +5V, output voltage swing is an excellent 0.3V to 3.8V with R_L = 500Ω.

At a gain of +2, the EL2245 and EL2445 have a -3dB bandwidth of 100MHz with a phase margin of 50°. Because of their conventional voltage-feedback topology, the EL2245 and EL2445 allow the use of reactive or non-linear elements in their feedback network. This versatility combined with low cost and 75mA of output-current drive make the EL2245 and EL2445 an ideal choice for price-sensitive applications requiring low power and high speed.

Features

- 100MHz gain-bandwidth
- Gain-of-2 stable
- Low supply current (per amplifier) - 5.2mA at V_S = ±15V
- Wide supply range - 2.5V to 36V
- High slew rate - 275V/µs
- Fast-settling - 80ns to 0.1% for a 10V step
- Low differential gain - 0.02% at A_V = +2, R_L = 150Ω
- Low differential phase - 0.07° at A_V = +2, R_L = 150Ω
- Wide output voltage swing - ±13.6V with V_S = ±15V, R_L = 1kΩ

Applications

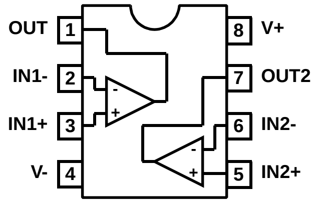
- Video amplifiers
- Single-supply amplifiers
- Active filters/integrators
- High speed signal processing
- ADC/DAC buffers
- Pulse/RF amplifiers
- Pin diode receivers
- Log amplifiers

Ordering Information

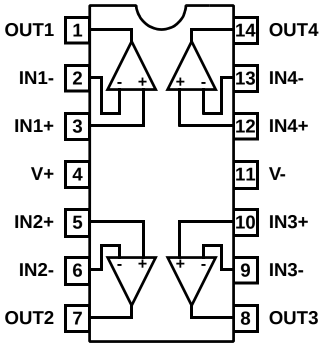
PART NUMBER	PACKAGE	TAPE & REEL	PKG. NO.
EL2245CN	8-Pin PDIP	-	MDP0031
EL2245CS	8-Pin SO	-	MDP0027
EL2245CS-T7	8-Pin SO	7”	MDP0027
EL2245CS-T13	8-Pin SO	13”	MDP0027
EL2445CN	14-Pin PDIP	-	MDP0031
EL2445CS	14-Pin SO (0.150")	-	MDP0027
EL2445CS-T7	14-Pin SO (0.150")	7”	MDP0027
EL2445CS-T13	14-Pin SO (0.150")	13”	MDP0027

Pinouts

EL2245
(8-PIN SO, PDIP)
TOP VIEW



EL2445
[14-PIN SO (0.150”), PDIP]
TOP VIEW



Absolute Maximum Ratings (T_A = 25°C)

Supply Voltage (V_S) . . . . ±18V or 36V
Input Voltage (V_{IN}) . . . . ±V_S
Differential Input Voltage (dV_{IN}) . . . . ±10V
Continuous Output Current 40mA

Power Dissipation (P_D) . . . . See Curves
Operating Temperature Range (T_A) . . . . -40°C to +85°C
Operating Junction Temperature (T_J) . . . . +150°C
Storage Temperature (T_{ST}) . . . . -65°C to +150°C

CAUTION: Stresses above those listed in “Absolute Maximum Ratings” may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

IMPORTANT NOTE: All parameters having Min/Max specifications are guaranteed. Typical values are for information purposes only. Unless otherwise noted, all tests are at the specified temperature and are pulsed tests, therefore: $T_J = T_C = T_A$

DC Electrical Specifications

V_S = ±15V, R_L = 1kΩ, unless otherwise specified.

PARAMETER	DESCRIPTION	CONDITION	TEMP	MIN	TYP	MAX	UNIT
V_{OS}	Input Offset Voltage	V_S = ±15V	25°C		0.5	4.0	mV
			T_{MIN}, T_{MAX}			6.0	mV
TCV_{OS}	Average Offset Voltage Drift	(Note 1)	All		10.0		µV/°C
I_B	Input Bias Current	V_S = ±15V	25°C		2.8	8.2	µA
			T_{MIN}, T_{MAX}			9.2	µA
		V_S = ±5V	25°C		2.8		µA
I_{OS}	Input Offset Current	V_S = ±15V	25°C		50	300	nA
			T_{MIN}, T_{MAX}			400	nA
		V_S = ±5V	25°C		50		nA
TCI_{OS}	Average Offset Current Drift	(Note 1)	All		0.3		nA/°C
A_{VOL}	Open-loop Gain	V_S = ±15V,V_{OUT} = ±10V, R_L = 1kΩ	25°C	1500	3000		V/V
			T_{MIN}, T_{MAX}	1500			V/V
		V_S = ±5V, V_{OUT} = ±2.5V, R_L = 500Ω	25°C		2500		V/V
		V_S = ±5V, V_{OUT} = ±2.5V, R_L = 150Ω	25°C		1750		V/V
PSRR	Power Supply Rejection Ratio	V_S = ±5V to ±15V	25°C	65	80		dB
			T_{MIN}, T_{MAX}	60			dB
CMRR	Common-mode Rejection Ratio	V_{CM} = ±12V, V_{OUT} = 0V	25°C	70	90		dB
			T_{MIN}, T_{MAX}	70			dB
CMIR	Common-mode Input Range	V_S = ±15V	25°C		±14.0		V
		V_S = ±5V	25°C		±4.2		V
		V_S = +5V	25°C		4.2/0.1		V
V_{OUT}	Output Voltage Swing	V_S = ±15V, R_L = 1kΩ	25°C	±13.4	±13.6		V
			T_{MIN}, T_{MAX}	±13.1			V
		V_S = ±15V, R_L = 500Ω	25°C	±12.0	±13.4		V
		V_S = ±5V, R_L = 500Ω	25°C	±3.4	±3.8		V
		V_S = ±5V, R_L = 150Ω	25°C		±3.2		V
		V_S = +5V, R_L = 500Ω	25°C	3.6/0.4	3.8/0.3		V
			T_{MIN}, T_{MAX}	3.5/0.5			V
I_{SC}	Output Short Circuit Current		25°C	40	75		mA
			T_{MIN}, T_{MAX}	35			mA

DC Electrical Specifications

V_S = ±15V, R_L = 1kΩ, unless otherwise specified. **(Continued)**

PARAMETER	DESCRIPTION	CONDITION	TEMP	MIN	TYP	MAX	UNIT
I_S	Supply Current (per amplifier)	V_S = ±15V, no load	25°C		5.2	7	mA
			T_{MIN}			7.6	mA
			T_{MAX}			7.6	mA
		V_S = ±5V, no load	25°C		5.0		mA
R_{IN}	Input Resistance	Differential	25°C		150		kΩ
		Common-mode	25°C		15		MΩ
C_{IN}	Input Capacitance	A_V = +1 @10MHz	25°C		1.0		pF
R_{OUT}	Output Resistance	A_V = +1	25°C		50		mΩ
PSOR	Power-supply Operating Range	Dual-supply	25°C	±2.0		±18.0	V
		Single-supply	25°C	2.5		36.0	V

NOTE:

1. Measured from T_{MIN} to T_{MAX}.

Closed-Loop AC Electrical Specifications

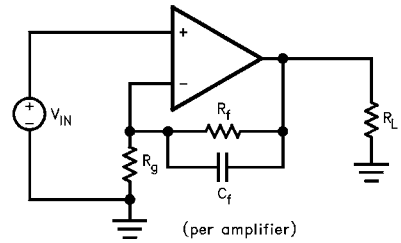
V_S = ±15V, A_V = +2, R_L = 1kΩ unless otherwise specified.

PARAMETER	DESCRIPTION	CONDITION	TEMP	MIN	TYP	MAX	UNIT
BW	-3dB Bandwidth (V_{OUT} = 0.4V_{PP})	V_S = ±15V, A_V = +2	25°C		100		MHz
		V_S = ±15V, A_V = -1	25°C		75		MHz
		V_S = ±15V, A_V = +5	25°C		20		MHz
		V_S = ±15V, A_V = +10	25°C		10		MHz
		V_S = ±15V, A_V = +20	25°C		5		MHz
		V_S = ±5V, A_V = +2	25°C		75		MHz
GBWP	Gain-bandwidth Product	V_S = ±15V	25°C		200		MHz
		V_S = ±5V	25°C		150		MHz
PM	Phase Margin	R_L = 1 kΩ, C_L = 10pF	25°C		50		°
CS	Channel Separation	f = 5MHz	25°C		85		dB
SR	Slew Rate (Note 1)	V_S = ±15V, R_L = 1kΩ	25°C	200	275		V/µs
		V_S = ±5V, R_L = 500Ω	25°C		200		V/µs
FPBW	Full-power Bandwidth (Note 2)	V_S = ±15V	25°C	3.2	4.4		MHz
		V_S = ±5V	25°C		12.7		MHz
t_R, t_F	Rise Time, Fall Time	0.1V step	25°C		3.0		ns
OS	Overshoot	0.1V step	25°C		20		%
t_{PD}	Propagation Delay		25°C		2.5		ns
t_S	Settling to +0.1% (A_V = +1)	V_S = ±15V, 10V step	25°C		80		ns
		V_S = ±5V, 5V step	25°C		60		ns
dG	Differential Gain (Note 3)	NTSC/PAL	25°C		0.02		%
dP	Differential Phase (Note 3)	NTSC/PAL	25°C		0.07		°
eN	Input Noise Voltage	10kHz	25°C		15.0		nV/√Hz
iN	Input Noise Current	10kHz	25°C		1.50		pA/√Hz

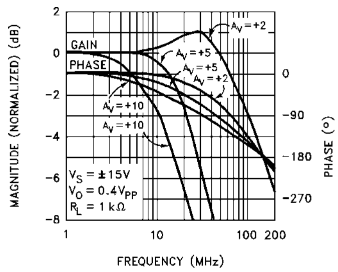
NOTES:

1. Slew rate is measured on rising edge.
2. For V_S = ±15V, V_{OUT} = 20V_{PP}. For V_S = ±5V, V_{OUT} = 5V_{PP}. Full-power bandwidth is based on slew rate measurement using: FPBW = SR/(2π * Vpeak).
3. Video performance measured at V_S = ±15V, A_V = +2 with 2 times normal video level across R_L = 150Ω. This corresponds to standard video levels across a back-terminated 75Ω load. For other values of R_L, see curves.

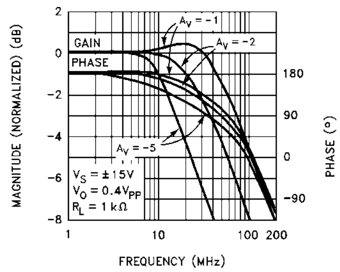
Test Circuit



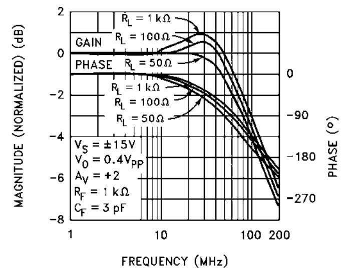
Typical Performance Curves



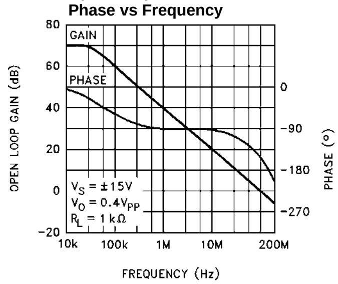
Non-Inverting Frequency Response



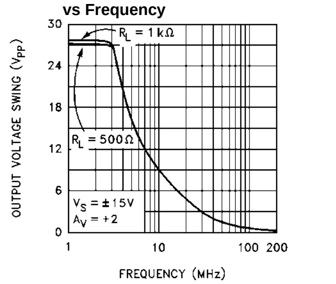
Inverting Frequency Response



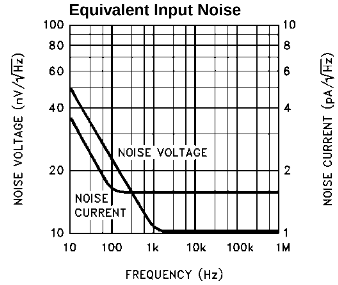
Frequency Response for Various Load Resistances



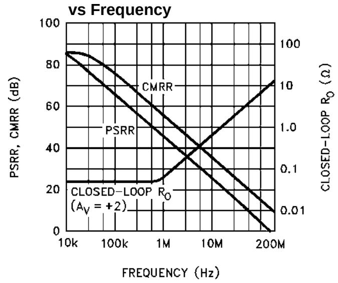
Open-Loop Gain and Phase vs Frequency



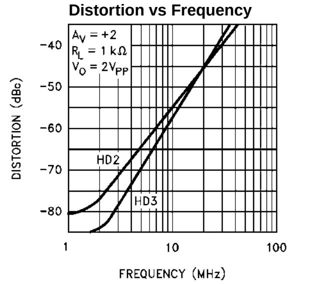
Output Voltage Swing vs Frequency



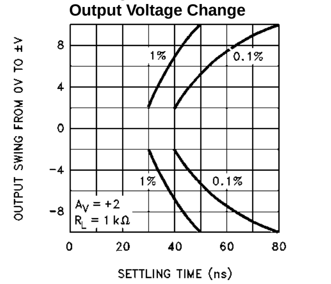
Equivalent Input Noise



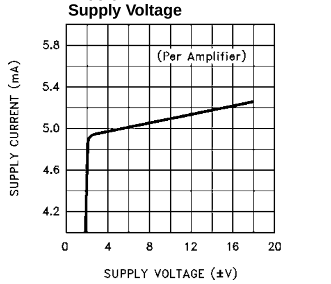
CMRR, PSRR and Closed-Loop Output Resistance vs Frequency



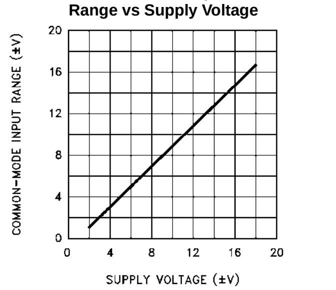
2nd and 3rd Harmonic Distortion vs Frequency



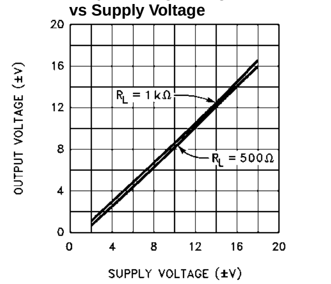
Settling Time vs Output Voltage Change



Supply Current vs Supply Voltage



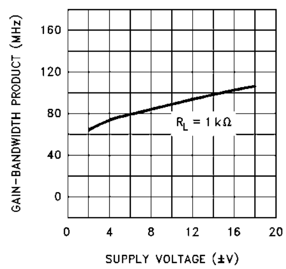
Common-Mode Input Range vs Supply Voltage



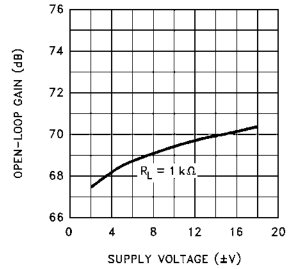
Output Voltage Range vs Supply Voltage

Typical Performance Curves (Continued)

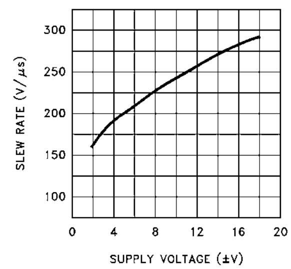
Gain-Bandwidth Product vs Supply Voltage



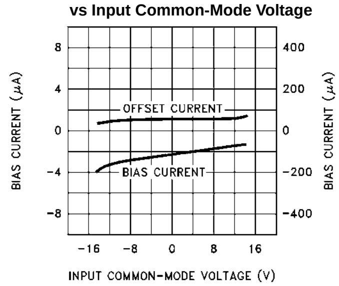
Open-Loop Gain vs Supply Voltage



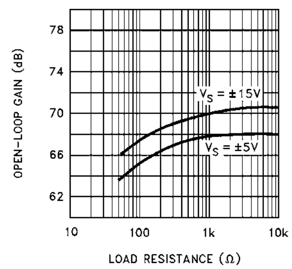
Slew-Rate vs Supply Voltage



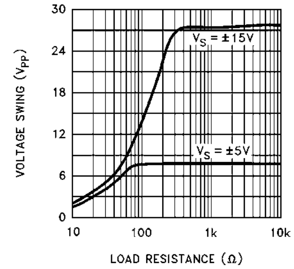
Bias and Offset Current vs Input Common-Mode Voltage



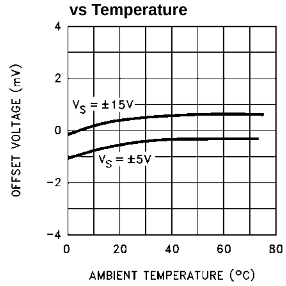
Open-Loop Gain vs Load Resistance



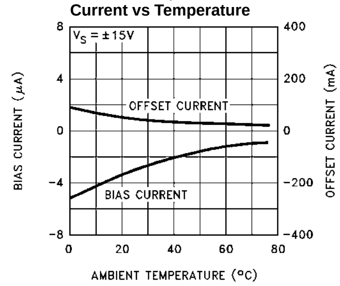
Voltage Swing vs Load Resistance



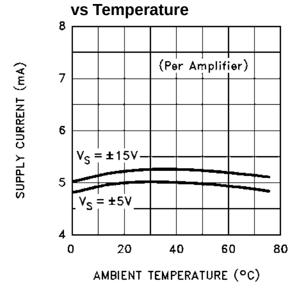
Offset Voltage vs Temperature



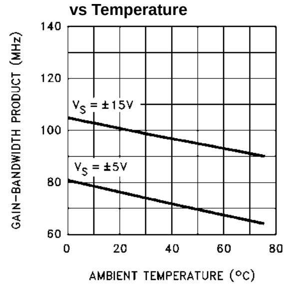
Bias and Output Current vs Temperature



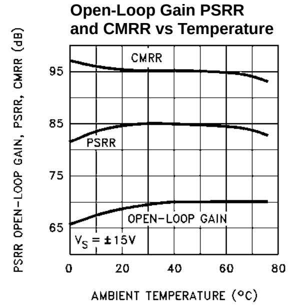
Supply Current vs Temperature



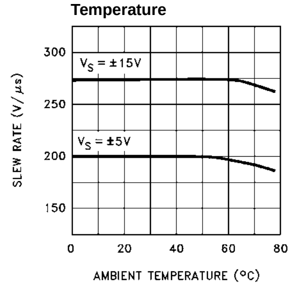
Gain-Bandwidth Product vs Temperature



Open-Loop Gain PSRR and CMRR vs Temperature

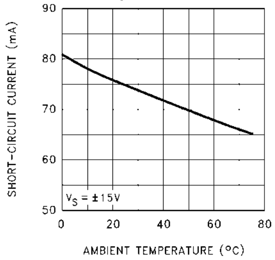


Slew Rate vs Temperature

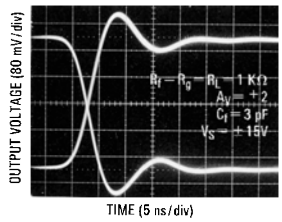


Typical Performance Curves (Continued)

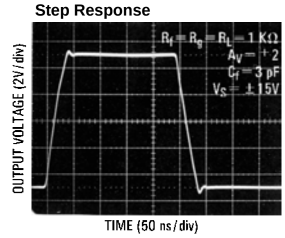
Short-Circuit Current vs Temperature



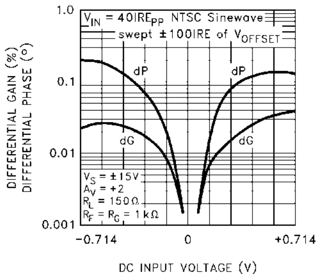
Small-Signal Step Response



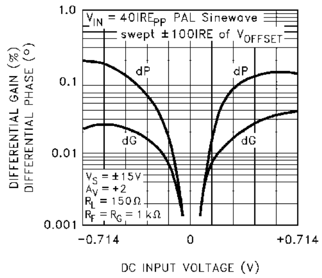
Large-Signal Step Response



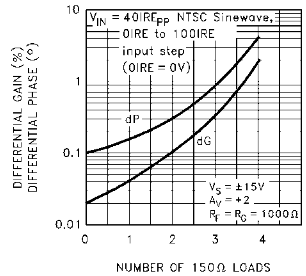
Differential Gain and Phase vs DC Input Offset at 3.58MHz



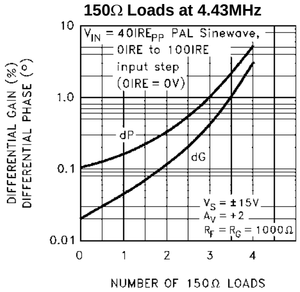
Differential Gain and Phase vs DC Input Offset at 4.43MHz



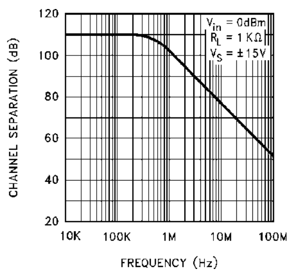
Differential Gain and Phase vs Number of 150Ω Loads at 3.58MHz



Differential Gain and Phase vs Number of 150Ω Loads at 4.43MHz

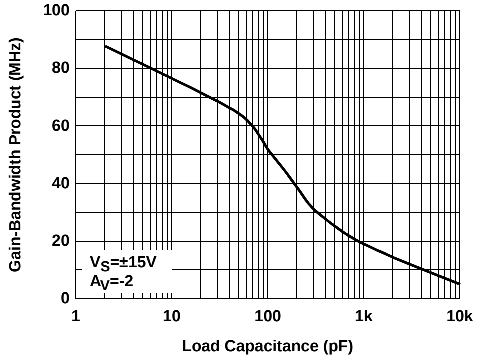


Channel Separation vs Frequency

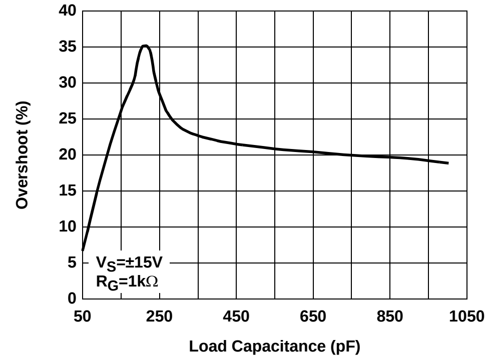


Typical Performance Curves (Continued)

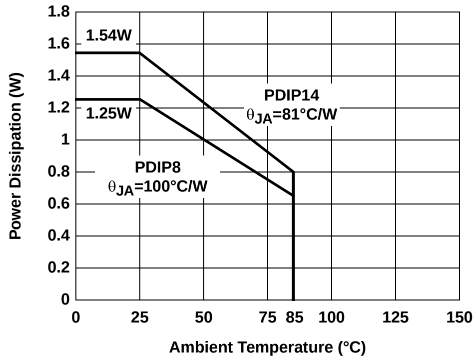
Gain-Bandwidth Product vs Load Capacitance



Overshoot vs Load Capacitance



Package Power Dissipation vs Ambient Temperature
JEDEC JESD51-3 Low Effective Thermal Conductivity (Single Layer) Test Board



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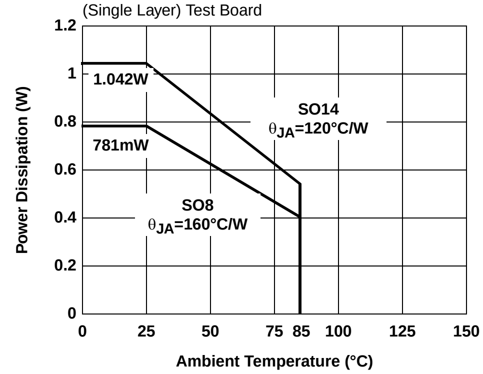
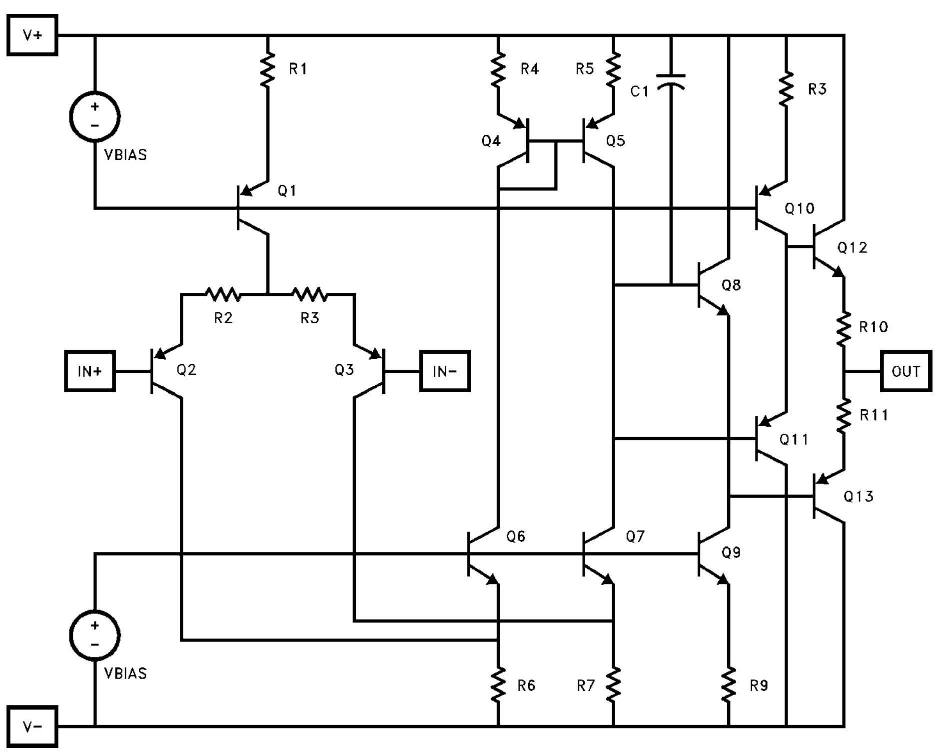
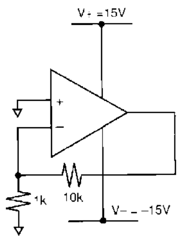
JEDEC JESD51-3 Low Effective Thermal Conductivity (Single Layer) Test Board



Simplified Schematic (Per Amplifier)



Burn-In Circuit (Per Amplifier)



ALL PACKAGES USE THE SAME SCHEMATIC

Applications Information

Product Description

The EL2245 and EL2445 are dual and quad low-power wideband monolithic operational amplifiers built on Elantec's proprietary high-speed complementary bipolar process. The EL2245 and EL2445 use a classical voltage-feedback topology which allows them to be used in a variety of applications where current-feedback amplifiers are not appropriate because of restrictions placed upon the feedback element used with the amplifier. The conventional topology of the EL2245 and EL2445 allows, for example, a capacitor to be placed in the feedback path, making it an excellent choice for applications such as active filters, sample-and-holds, or integrators. Similarly, because of the ability to use diodes in the feedback network, the EL2245 and EL2445 are an excellent choice for applications such as fast log amplifiers.

Power Dissipation

With the wide power supply range and large output drive capability of the EL2245 and EL2445, it is possible to exceed the 150°C maximum junction temperatures under certain load and power-supply conditions. It is therefore important to calculate the maximum junction temperature (T_{JMAX}) for all applications to determine if power supply voltages, load conditions, or package type need to be modified for the EL2245 and EL2445 to remain in the safe operating area. These parameters are related as follows:

$$T_{JMAX} = T_{MAX} + (\Theta_{JA} \times PD_{MAXTOTAL})$$

where:

$PD_{MAXTOTAL}$ is the sum of the maximum power dissipation of each amplifier in the package (PD_{MAX}). PDmax for each amplifier can be calculated as follows:

$$PD_{MAX} = 2 \times V_S \times I_{SMAX} + (V_S - V_{OUTMAX}) \times \frac{V_{OUTMAX}}{R_L}$$

where:

T_{MAX} = Maximum ambient temperature

θ_{JA} = Thermal resistance of the package

PD_{MAX} = Maximum power dissipation of each amplifier

V_S = Supply voltage

I_{SMAX} = Maximum supply current of each amplifier

V_{OUTMAX} = Maximum output voltage swing of the application

R_L = Load resistance

To serve as a guide for the user, we can calculate maximum allowable supply voltages for the example of the video cable-driver below since we know that T_{JMAX} = 150°C, T_{MAX} = 85°C, I_{SMAX} = 7.6mA per amplifier, and the package θ_{JA}s are shown in Table 1. If we assume (for this example) that we are driving a back-terminated video cable, then the maximum average value (over duty-cycle) of V_{OUTMAX} is 1.4V, and R_L = 150Ω, giving the results seen in Table 1.

TABLE 1.

PART	PACKAGE	Θ_{JA}	MAX PDISS @T_{MAX}	MAX V_S
DUALS				
EL2245CN	PDIP8	100°C/W	0.650W @85°C	±16.6V
EL2245CS	SO8	160°C/W	0.406W @85°C	±10.5V
QUADS				
EL2445CN	PDIP14	81°C/W	0.802W @85°C	±11.5V
EL2445CS	SO14	120°C/W	0.542W @85°C	±7.5V

Single-Supply Operation

The EL2245 and EL2445 have been designed to have a wide input and output voltage range. This design also makes the EL2245 and EL2445 an excellent choice for single-supply operation. Using a single positive supply, the lower input voltage range is within 100mV of ground (R_L = 500Ω), and the lower output voltage range is within 300mV of ground. Upper input voltage range reaches 4.2V, and output voltage range reaches 3.8V with a 5V supply and R_L = 500Ω. This results in a 3.5V output swing on a single 5V supply. This wide output voltage range also allows single-supply operation with a supply voltage as high as 36V or as low as 2.5V. On a single 2.5V supply, the EL2245 and EL2445 still have 1V of output swing.

Gain-Bandwidth Product and the -3dB Bandwidth

The EL2245 and EL2445 have a bandwidth at gain-of-2 of 100MHz while using only 5.2mA of supply current per amplifier. For gains greater than 4, their closed-loop -3dB bandwidth is approximately equal to the gain-bandwidth product divided by the noise gain of the circuit. For gains less than 4, higher-order poles in the amplifiers' transfer function contribute to even higher closed loop bandwidths. For example, the EL2245 and EL2445 have a -3dB bandwidth of 100MHz at a gain of +2, dropping to 20MHz at a gain of +5. It is important to note that the EL2245 and EL2445 have been designed so that this “extra” bandwidth in low-gain applications does not come at the expense of stability. As seen in the typical performance curves, the EL2245 and EL2445 in a gain of +2 only exhibit 1.0dB of peaking with a 1kΩ load.

Video Performance

An industry-standard method of measuring the video distortion of components such as the EL2245/ EL2445 is to measure the amount of differential gain (dG) and differential phase (dP) that they introduce. To make these measurements, a 0.286V_{PP} (40 IRE) signal is applied to the device with 0V DC offset (0 IRE) at either 3.58MHz for NTSC or 4.43MHz for PAL. A second measurement is then made at 0.714V DC offset (100 IRE). Differential gain is a measure of the change in amplitude of the sine wave, and is measured in percent. Differential phase is a measure of the change in phase, and is measured in degrees.

For signal transmission and distribution, a back-terminated cable (75Ω in series at the drive end, and 75Ω to ground at the receiving end) is preferred since the impedance match at both ends will absorb any reflections. However, when double termination is used, the received signal is halved; therefore a gain of 2 configuration is typically used to compensate for the attenuation.

The EL2245 and EL2445 have been designed as an economical solution for applications requiring low video distortion. They have been thoroughly characterized for video performance in the topology described above, and the results have been included as typical dG and dP specifications and as typical performance curves. In a gain of +2, driving 150Ω, with standard video test levels at the input, the EL2245 and EL2445 exhibit dG and dP of only 0.02% and 0.07° at NTSC and PAL. Because dG and dP can vary with different DC offsets, the video performance of the EL2245 and EL2445 has been characterized over the entire DC offset range from -0.714V to +0.714V. For more information, refer to the curves of dG and dP vs DC Input Offset.

Output Drive Capability

The EL2245 and EL2445 have been designed to drive low impedance loads. They can easily drive 6V_{PP} into a 150Ω load. This high output drive capability makes the EL2245 and EL2445 an ideal choice for RF, IF and video applications. Furthermore, the current drive of the EL2245 and EL2445 remains a minimum of 35mA at low temperatures.

Printed-Circuit Layout

The EL2245 and EL2445 are well behaved, and easy to apply in most applications. However, a few simple techniques will help assure rapid, high quality results. As with any high-frequency device, good PCB layout is necessary for optimum performance. Ground-plane construction is highly recommended, as is good power supply bypassing. A 0.1µF ceramic capacitor is recommended for bypassing both supplies. Lead lengths should be as short as possible, and bypass capacitors should be as close to the device pins as possible. For good AC performance, parasitic capacitances should be kept to a minimum at both inputs and at the output. Resistor values should be kept under 5kΩ because of the RC time constants associated with the parasitic capacitance. Metal-film and carbon resistors are both acceptable, use of wire-wound resistors is not recommended because of their parasitic inductance. Similarly, capacitors should be low-inductance for best performance.

The EL2245 and EL2445 Macromodel

This macromodel has been developed to assist the user in simulating the EL2245 and EL2445 with surrounding circuitry. It has been developed for the PSPICE simulator (copywritten by the Microsim Corporation), and may need to be rearranged for other simulators. It approximates DC, AC, and transient response for resistive loads, but does not accurately model capacitive loading. This model is slightly more complicated than the models used for low-frequency op-amps, but it is much more accurate for AC analysis.

The model does not simulate these characteristics accurately:

- Noise
- Settling time
- Non-linearities
- Temperature effects
- Manufacturing variations
- CMRR
- PSRR

EL2245 and EL2445 Macromodel

```
* Connections: +input
*                     |     -input
*                     |     |     +Vsupply
*                     |     |     |     -Vsupply
*                     |     |     |     |     output
*                     |     |     |     |     |
.subckt M2245  3     2     7     4     6
*
* Input stage
*
ie 7 37 1mA
r6 36 37 400
r7 38 37 400
rc1 4 30 850
rc2 4 39 850
q1 30 3 36 qp
q2 39 2 38 qpa
ediff 33 0 39 30 1.0
rdiff 33 0 1Meg
*
* Compensation Section
*
ga 0 34 33 0 1m
rh 34 0 2Meg
ch 34 0 1.3pF
rc 34 40 1K
cc 40 0 1pF
*
* Poles
*
ep 41 0 40 0 1
rpa 41 42 200
cpa 42 0 1pF
rpb 42 43 200
cpb 43 0 1pF
*
* Output Stage
*
ios1 7 50 1.0mA
ios2 51 4 1.0mA
q3 4 43 50 qp
q4 7 43 51 qn
q5 7 50 52 qn
q6 4 51 53 qp
ros1 52 6 25
ros2 6 53 25
*
* Power Supply Current
*
ips 7 4 2.7mA
*
* Models
*
.model qn npn(is=800E-18 bf=200 tf=0.2nS)
.model qpa pnp(is=864E-18 bf=100 tf=0.2nS)
.model qp pnp(is=800E-18 bf=125 tf=0.2nS)
.ends
```

EL2245 and EL2445 Macromodel (Continued)